

60 V, 5.7 A PNP low V_{CEsat} (BISS) transistor Rev. 01 — 31 March 2010

Product data sheet

Product profile 1.

1.1 General description

PNP low V_{CEsat} Breakthrough In Small Signal (BISS) transistor in a SOT223 (SC-73) medium power Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4041NZ.

1.2 Features and benefits

- Very low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- High energy efficiency due to less heat generation
- AEC-Q101 qualified
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors

1.3 Applications

- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

1.4 Quick reference data

Table 1. **Quick reference data**

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|--|--|--------------|-----|------|------|
| V_{CEO} | collector-emitter voltage | open base | - | - | -60 | V |
| I _C | collector current | | - | - | -5.7 | А |
| I _{CM} | peak collector current | single pulse; $t_p \leq 1 \text{ ms}$ | - | - | -15 | А |
| R _{CEsat} | collector-emitter saturation resistance | l _C = –5 A; l _B = –500 mA | <u>[1]</u> _ | 29 | 43.5 | mΩ |

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

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Pinning information 2.

| Table 2. | Pinning | | |
|----------|-------------|--------------------|----------------|
| Pin | Description | Simplified outline | Graphic symbol |
| 1 | base | | |
| 2 | collector | | 2, 4 |
| 3 | emitter | | 1- |
| 4 | collector | | 3 |
| | | | sym028 |

Ordering information 3.

| Table 3. Ordering information | | | | | |
|---------------------------------------|---------|---|---------|--|--|
| Type number | Package | le | | | |
| | Name | Description | Version | | |
| PBSS4041PZ | SC-73 | plastic surface-mounted package with increased heat sink; 4 leads | SOT223 | | |

Marking 4.

| Table 4. Marking codes | |
|--------------------------|--------------|
| Type number | Marking code |
| PBSS4041PZ | PB4041PZ |

Limiting values 5.

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| | | 0, | , | | |
|------------------|---------------------------|---------------------------------------|-----|------|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| V _{CBO} | collector-base voltage | open emitter | - | -60 | V |
| V _{CEO} | collector-emitter voltage | open base | - | -60 | V |
| V _{EBO} | emitter-base voltage | open collector | - | -5 | V |
| I _C | collector current | | - | -5.7 | А |
| I _{CM} | peak collector current | single pulse; $t_p \leq 1 \text{ ms}$ | - | -15 | А |
| I _B | base current | | - | -1 | А |

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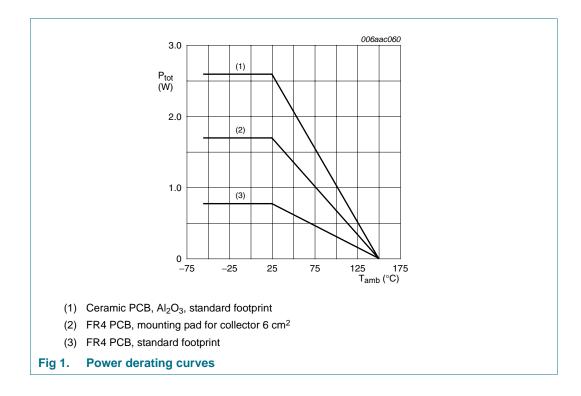
| Symbol | Parameter | Conditions | Min | Max | Unit |
|--|------------------------------|------------|-------|------|------|
| P _{tot} total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | [1] - | 770 | mW | |
| | | | [2] _ | 1700 | mW |
| | | | [3] _ | 2600 | mW |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -55 | +150 | °C |
| T _{stg} | storage temperature | | -65 | +150 | °C |

Table 5 Limiting values continued

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm². [2]

Device mounted on a ceramic PCB, AI_2O_3 , standard footprint. [3]



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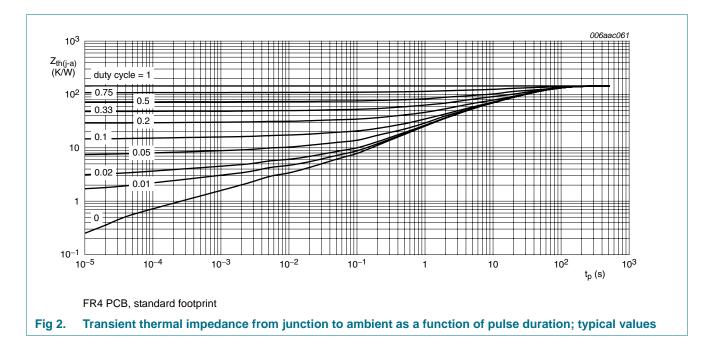
6. Thermal characteristics

| Table 6. | Thermal characteristics | | | | | |
|-----------------------|--|-------------|--------------|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| -ui(j-a) | thermal resistance from | in free air | <u>[1]</u> _ | - | 160 | K/W |
| | junction to ambient | | [2] _ | - | 75 | K/W |
| | | | <u>[3]</u> _ | - | 50 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | - | - | 11 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

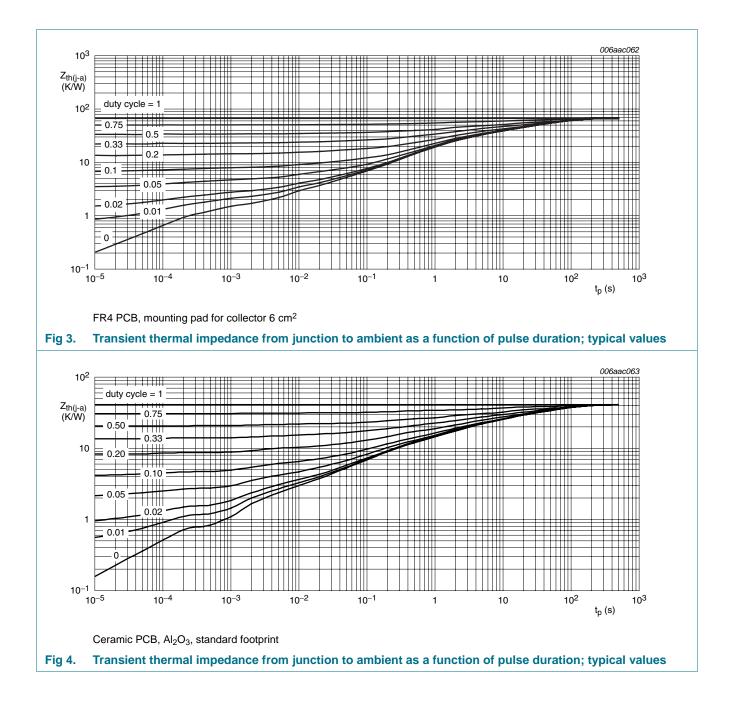
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

[3] Device mounted on a ceramic PCB, AI_2O_3 , standard footprint.



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60 V, 5.7 A PNP low V_{CEsat} (BISS) transistor

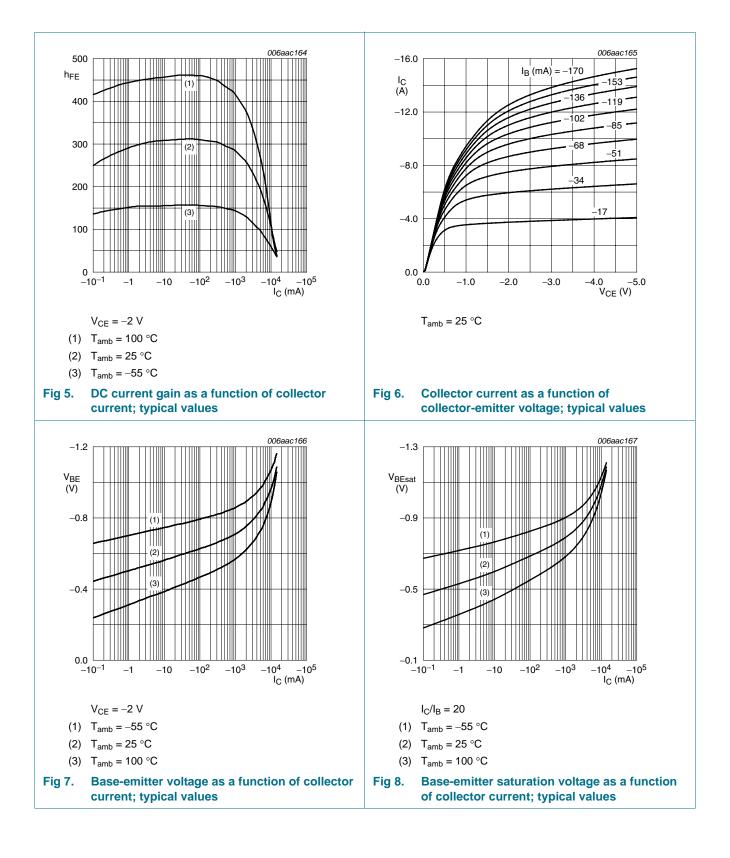
7. Characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--------------------|---|--|------------|------|-------|-------|------|
| I _{CBO} | collector-base cut-off | $V_{CB} = -60 \text{ V}; I_E = 0 \text{ A}$ | | - | - | -100 | nA |
| | current | $\label{eq:VCB} \begin{array}{l} V_{CB} = -60 \ V; \ I_E = 0 \ A; \\ T_j = 150 \ ^\circ C \end{array}$ | | - | - | -55 | μA |
| I _{CES} | collector-emitter cut-off current | $V_{CE} = -48 \text{ V}; \text{V}_{BE} = 0 \text{ V}$ | | - | - | -100 | nA |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$ | | - | - | -100 | nA |
| h _{FE} | DC current gain | | [1] | | | | |
| | | $V_{CE} = -2 V;$ $I_C = -500 mA$ | | 200 | 300 | - | |
| | | $V_{CE} = -2 \text{ V}; \text{ I}_{C} = -1 \text{ A}$ | | 200 | 300 | - | |
| | | $V_{CE} = -2 \text{ V}; \text{ I}_{C} = -2 \text{ A}$ | | 200 | 300 | - | |
| | | $V_{CE} = -2 \text{ V}; \text{ I}_{C} = -4 \text{ A}$ | | 150 | 250 | - | |
| | | $V_{CE} = -2 \text{ V}; \text{ I}_{C} = -6 \text{ A}$ | | 120 | 200 | - | |
| V _{CEsat} | collector-emitter | | [1] | | | | |
| | saturation voltage | $I_{\rm C} = -1$ A; $I_{\rm B} = -50$ mA | | - | -42 | -63 | mV |
| | | I_{C} = -1 A; I_{B} = -10 mA | | - | -82 | -125 | mV |
| | | I_{C} = -2 A; I_{B} = -40 mA | | - | -98 | -150 | mV |
| | | I_{C} = -4 A; I_{B} = -200 mA | | - | -130 | -195 | mV |
| | $I_{C} = -4 \text{ A}; I_{B} = -400 \text{ mA}$ | | - | -115 | -175 | mV | |
| | | $I_{C} = -6 \text{ A}; I_{B} = -300 \text{ mA}$ | | - | -190 | -285 | mV |
| R _{CEsat} | collector-emitter saturation resistance | $I_{C} = -5 \text{ A}; I_{B} = -500 \text{ mA}$ | <u>[1]</u> | - | 29 | 43.5 | mΩ |
| V _{BEsat} | base-emitter | $I_{C} = -1$ A; $I_{B} = -100$ mA | [1] | - | -0.82 | -0.9 | V |
| | saturation voltage | $I_{C} = -4 \text{ A}; I_{B} = -400 \text{ mA}$ | [1] | - | -0.98 | -1.05 | V |
| V _{BEon} | base-emitter turn-on voltage | $V_{CE} = -2 V; I_C = -2 A$ | <u>[1]</u> | - | -0.74 | -0.85 | V |
| t _d | delay time | $V_{CC} = -12.5 V;$ | | - | 60 | - | ns |
| t _r | rise time | $I_{C} = -1 \text{ A}; I_{Bon} = -0.05 \text{ A};$ $I_{Boff} = 0.05 \text{ A}$ | | - | 60 | - | ns |
| t _{on} | turn-on time | B ^{off} – 0.03 A | | - | 120 | - | ns |
| t _s | storage time | | | - | 530 | - | ns |
| t _f | fall time | | | - | 100 | - | ns |
| t _{off} | turn-off time | | | - | 630 | - | ns |
| f _T | transition frequency | $V_{CE} = -10 V;$ $I_{C} = -100 mA;$ f = 100 MHz | | - | 110 | - | MHz |
| C _c | collector capacitance | V _{CB} = -10 V; I _E = i _e = 0 A; f = 1 MHz | | - | 85 | - | pF |

 $\label{eq:point} \begin{tabular}{ll} \begin{$

PBSS4041PZ

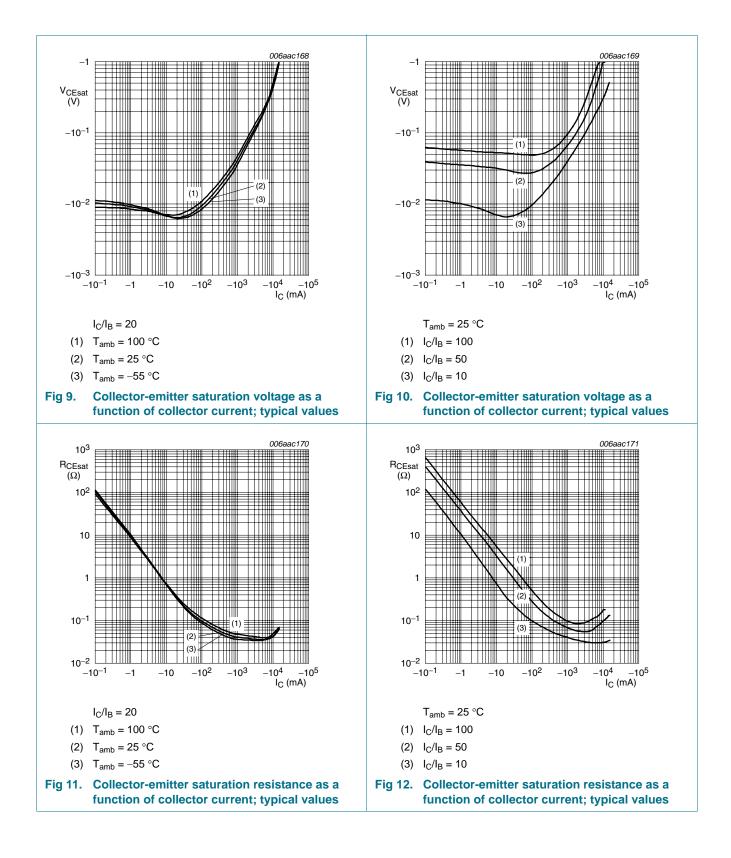
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PBSS4041PZ_1
Product data sheet

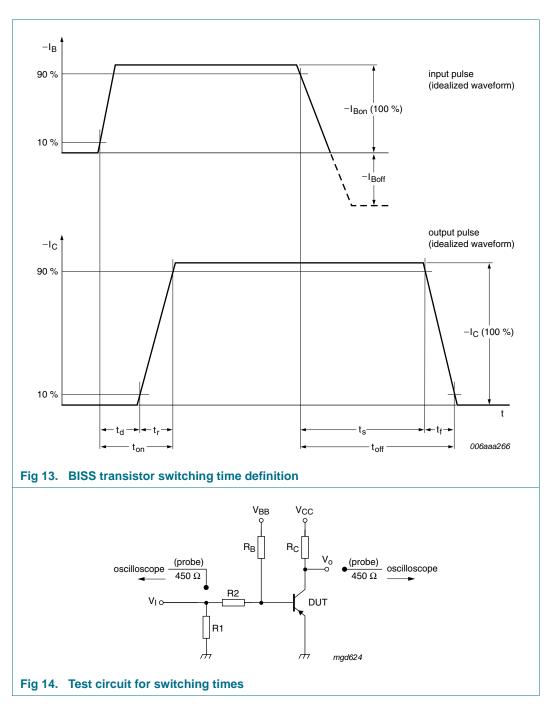
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8. Test information

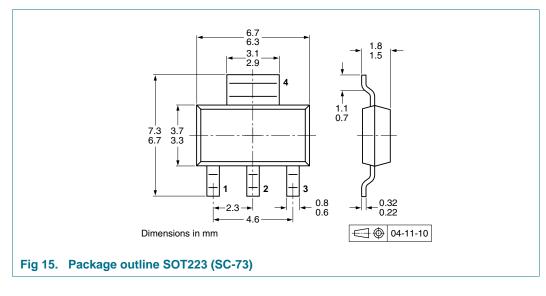


8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

Table 8. Packing methods

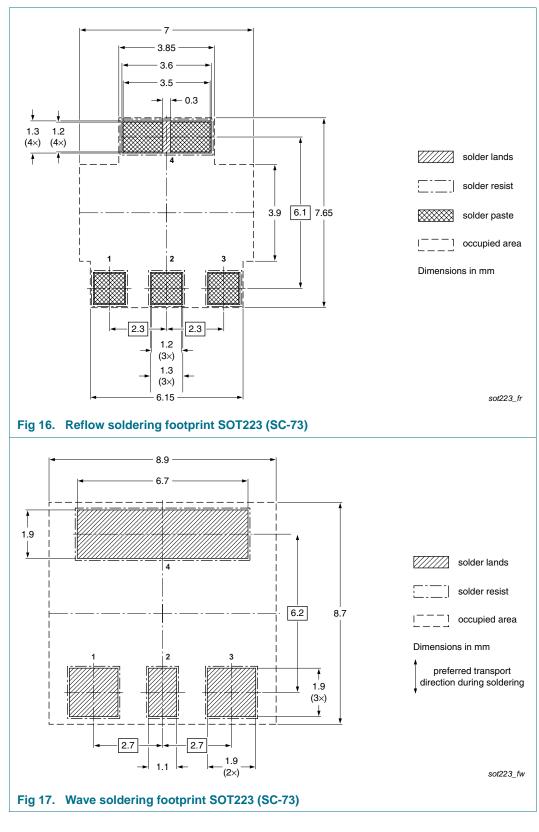
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description | Packing | quantity |
|-------------|---------|---------------------------------|---------|----------|
| | | | 1000 | 4000 |
| PBSS4041PZ | SOT223 | 8 mm pitch, 12 mm tape and reel | -115 | -135 |

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

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11. Soldering



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12. Revision history

| Table 9. Revision h | istory | | | |
|---------------------|--------------|--------------------|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| PBSS4041PZ_1 | 20100331 | Product data sheet | - | - |

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13. Legal information

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| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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